

Features

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

I_{F(AV)} **1600 A**
V_{RRM} **2100~3000 V**
I_{FSM} **32 kA**
I²t **5120 10³A²s**

Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180°half sine wave 50Hz Double side cooled,	150			1600	A
V _{RRM}	Repetitive peak reverse voltage	tp=10ms	150	2100		3000	V
I _{RRM}	Repetitive peak current	at V _{RRM}	150			80	mA
I _{FSM}	Surge forward current	10ms half sine wave V _R =0.6V _{RRM}	150			32	kA
I ² t	I ² t for fusing coordination					5120	A ² s*10 ³
V _{FO}	Threshold voltage		150			0.78	V
r _F	Forward slope resistance					0.20	mΩ
V _{FM}	Peak forward voltage	I _{FM} =5000A, F=24kN	25			1.60	V
Q _{rr}	Recovery charge	I _{FM} =2000A, tp=2000μs, di/dt=-20A/μs, V _R =50V	150		3500		μC
R _{th(j-c)}	Thermal resistance Junction to case	DC double side cooled Clamping force 24kN				0.019	°C/W
R _{th(c-h)}	Thermal resistance case to heat sink					0.005	
F _m	Mounting force			19		26	kN
T _{stg}	Stored temperature			-40		150	°C
W _t	Weight				380		g
Outline		P36					

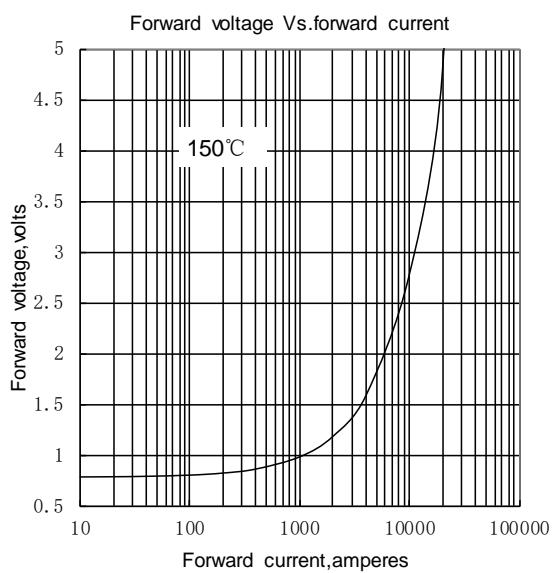


Fig.1

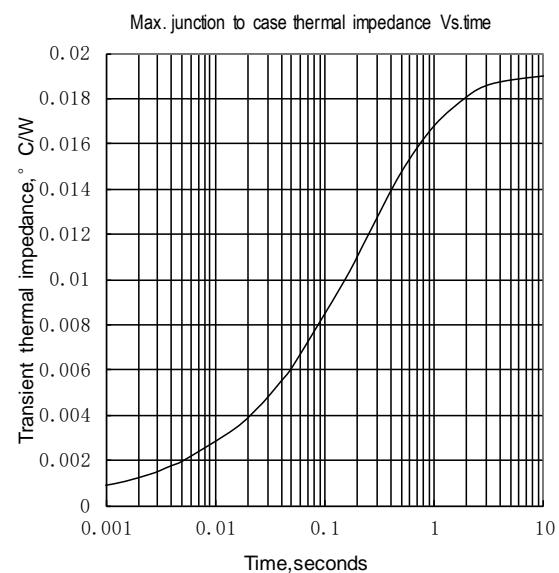


Fig.2

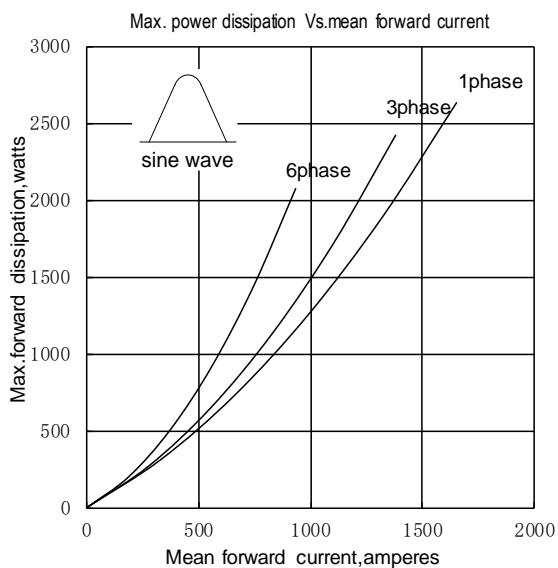


Fig.3

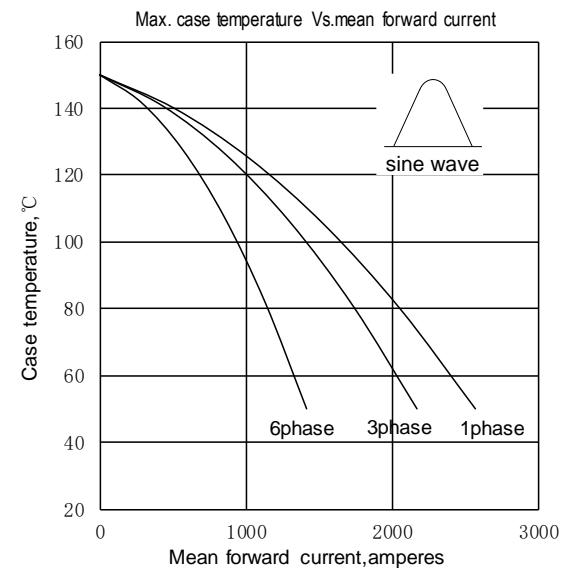


Fig.4

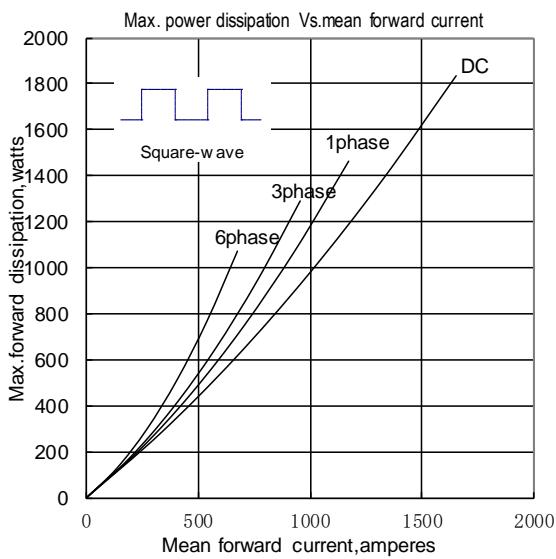


Fig.5

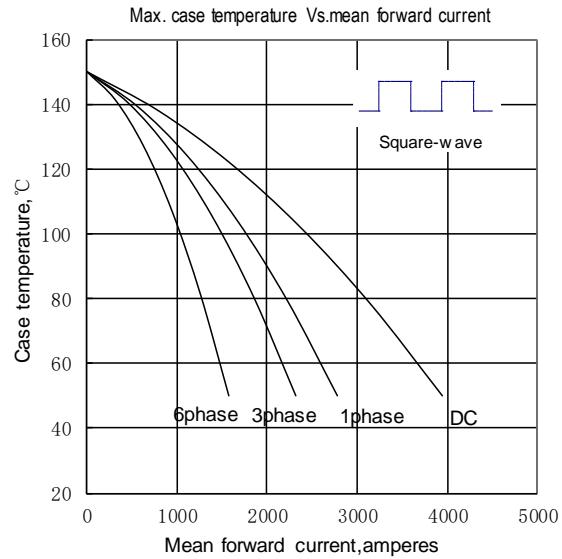


Fig.6

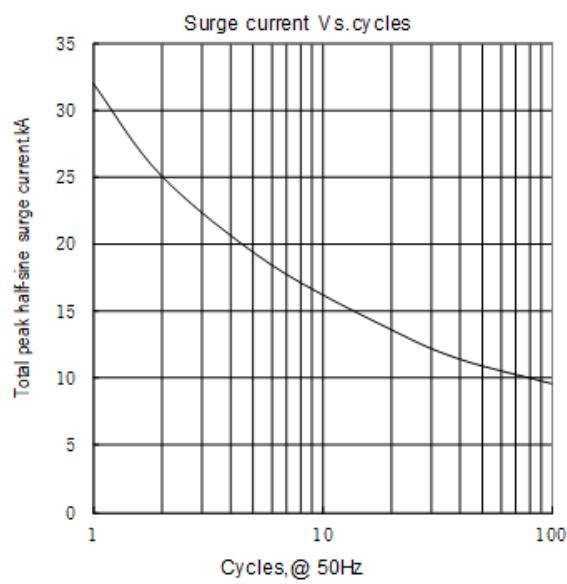
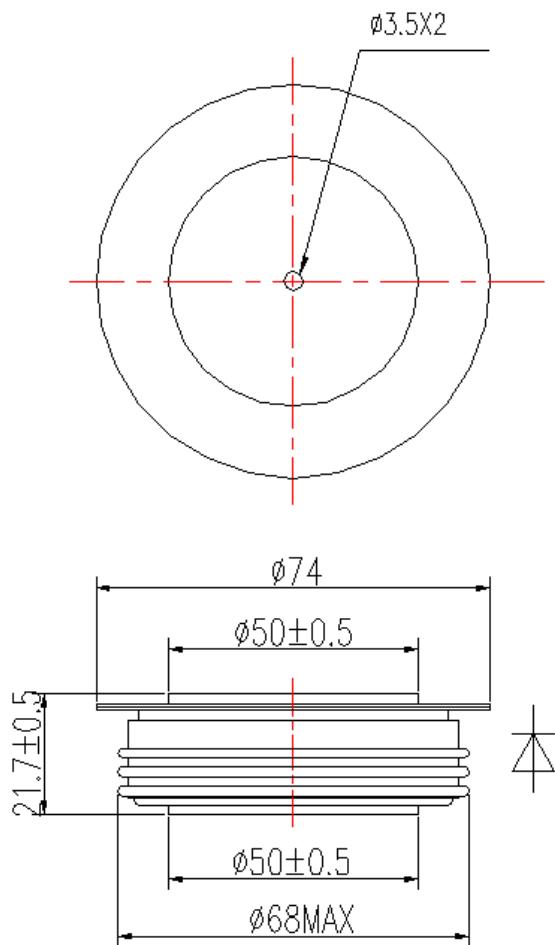


Fig.7



Nips reserves the right to change specifications without notice.